

November 1988 Revised December 1998

74ACT563 Octal Latch with 3-STATE Outputs

General Description

The ACT563 is a high-speed octal latch with buffered common Latch Enable (LE) and buffered common Output Enable ($\overline{\text{OE}}$) inputs.

Features

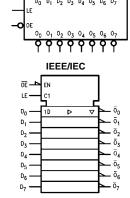
- I_{CC} and I_{OZ} reduced by 50%
- Inputs and outputs on opposite sides of package allow easy interface with microprocessors
- Useful as input or output port for microprocessors
- Functionally identical to ACT573 but with inverted out-
- Outputs source/sink 24 mA
- ACT563 has TTL-compatible inputs

Ordering Code:

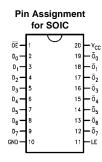
	Order Number	Package Number	Package Description
١	74ACT563SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Pin Descriptions

Pin Names	Description			
D ₀ –D ₇	Data Inputs			
LE	Latch Enable Input			
ŌE	3-STATE Output Enable Input			
$\overline{O}_0 - \overline{O}_7$	3-STATE Latch Outputs			

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Functional Description

The ACT563 contains eight D-type latches with 3-STATE complementary outputs. When the Latch Enable (LE) input is HIGH, data on the D_{n} inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW the latches store the information that was present on the D inputs at setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE buffers are controlled by the Output Enable (OE) input. When OE is LOW, the buffers are in the bi-state mode. When $\overline{\text{OE}}$ is HIGH the buffers are in the high impedance mode but that does not interfere with entering new data into the latches.

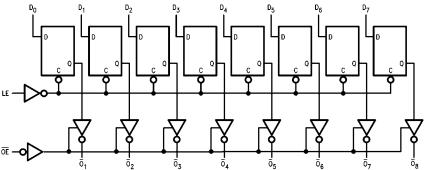
Function Table

Inputs			Internal	Outputs	Function
OE	LE	D	Q	0	
Н	Х	Χ	Х	Z	High-Z
Н	Н	L	Н	Z	High-Z
Н	Н	Н	L	Z	High-Z
Н	L	Χ	NC	Z	Latched
L	Н	L	Н	Н	Transparent
L	Н	Н	L	L	Transparent
L	L	Χ	NC	NC	Latched

- H = HIGH Voltage Level L = LOW Voltage Level

- X = Immaterial
 Z = High Impedance
 NC = No Change

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC}) -0.5V to +7.0V

DC Input Diode Current (I_{IK})

 $\begin{array}{ccc} \rm V_I = -0.5V & -20~mA \\ \\ \rm V_I = V_{CC} + 0.5V & +20~mA \\ \\ \rm DC~Input~Voltage~(V_I) & -0.5V~to~V_{CC} + 0.5V \end{array}$

DC Output Diode Current (I_{OK})

 $V_{O} = -0.5V$ -20 mA $V_{O} = V_{CC} + 0.5V$ +20 mA

DC Output Voltage (V_O) -0.5V to $V_{CC} + 0.5V$

DC Output Source

or Sink Current (I_O) $\pm 50 \text{ mA}$

DC V_{CC} or Ground Current

per Output Pin (I_{CC} or I_{GND}) ± 50 mA Storage Temperature (T_{STG}) -65° C to +150 $^{\circ}$ C

Junction Temperature (T_J) (PDIP) 140°C

Recommended Operating Conditions

Minimum Input Edge Rate ($\Delta V/\Delta t$)

 $V_{\mbox{\scriptsize IN}}$ from 0.8V to 2.0V

 V_{CC} @ 4.5V, 5.5V 125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACTTM circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V _{CC}	V _{CC}		T _A =-40°C to +85°C	Units	Conditions	
		(V)	Typ Guaranteed Limits		aranteed Limits			
V _{IH}	Minimum HIGH Level	4.5	1.5	2.0	2.0	V	V _{OUT} = 0.1V	
	Input Voltage	5.5	1.5	2.0	2.0		or V _{CC} – 0.1V	
V _{IL}	Maximum LOW Level	4.5	1.5	8.0	0.8	V	V _{OUT} = 0.1V	
	Input Voltage	5.5	1.5	0.8	0.8		or V _{CC} – 0.1V	
V _{OH}	Minimum HIGH Level	4.5	4.49	4.4	4.4	V	I _{OUT} = -50 μA	
	Output Voltage	5.5	5.49	5.4	5.4			
							$V_{IN} = V_{IL}$ or V_{IH}	
		4.5		3.86	3.76	V	$I_{OH} = -24 \text{ mA}$	
		5.5		4.86	4.76		$I_{OH} = -24 \text{ mA (Note 2)}$	
V _{OL}	Maximum LOW Level	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50 \mu A$	
	Output Voltage	5.5	0.001	0.1	0.1			
							$V_{IN} = V_{IL}$ or V_{IH}	
		4.5		0.36	0.44	V	I _{OL} = 24 mA	
		5.5		0.36	0.44		I _{OL} = 24 mA (Note 2)	
I _{IN}	Maximum Input	5.5		±0.1	±1.0	μА	$V_I = V_{CC}$, GND	
	Leakage Current							
I _{OZ}	Maximum 3-STATE	5.5		±0.25	±2.5	μА	$V_I = V_{IL}, V_{IH}$	
	Current						$V_O = V_{CC}$, GND	
I _{CCT}	Maximum	5.5	0.6		1.5	mA	$V_{I} = V_{CC} - 2.1V$	
	I _{CC} /Input							
I _{OLD}	Minimum Dynamic	5.5			75	mA	V _{OLD} = 1.65V Max	
I _{OHD}	Output Current (Note 3)	5.5		1	-75	mA	V _{OHD} = 3.85V Min	
I _{CC}	Maximum Quiescent	5.5		4.0	40.0	μΑ	$V_{IN} = V_{CC}$	
	Supply Current						or GND	

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics

	Parameter	V _{CC}	V_{CC} $T_A = +25^{\circ}C$ (V) $C_L = 50 \text{ pF}$			$T_A = -40^{\circ}\text{C} \text{ to } +85^{\circ}\text{C}$ $C_L = 50 \text{ pF}$		Units
Symbol		(V)						
		(Note 4)	Min	Тур	Max	Min	Max	
t _{PLH}	Propagation Delay	5.0	3.0	7.0	11.5	2.5	12.5	ns
	D_n to \overline{O}_n							
t _{PHL}	Propagation Delay	5.0	3.0	6.0	10.0	2.5	11.0	ns
	D_n to \overline{O}_n							
t _{PLH}	Propagation Delay	5.0	3.0	6.5	10.5	2.5	11.5	ns
	LE to \overline{O}_n							
t _{PHL}	Propagation Delay	5.0	2.5	5.5	9.5	2.0	10.5	ns
	LE to \overline{O}_n							
t _{PZH}	Output Enable Time	5.0	2.5	5.5	9.0	2.0	10.0	ns
t _{PZL}	Output Enable Time	5.0	2.0	5.5	8.5	2.0	9.5	ns
t _{PHZ}	Output Disable Time	5.0	3.5	6.5	10.5	2.5	11.5	ns
t _{PLZ}	Output Disable Time	5.0	2.0	4.5	8.0	1.0	8.5	ns

Note 4: Voltage Range 5.0 is 5.0V ±0.5V

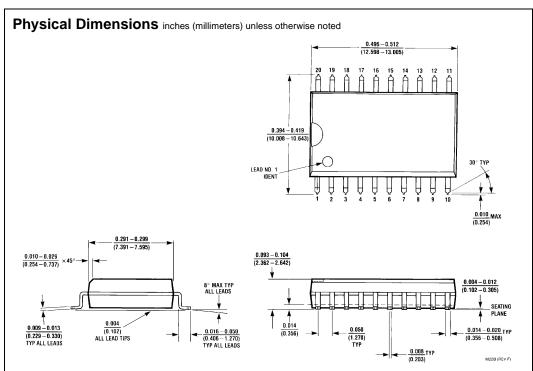
AC Operating Requirements

Symbol	Parameter	v _{cc} (v)	$T_A = +25^{\circ}C$ $C_L = 50 \text{ pF}$		$T_A = -40$ °C to $+85$ °C $C_L = 50$ pF	Units
		(Note 5)	Typ Guar		ranteed Minimum	
t _s	Setup Time, HIGH or LOW D _n to LE	5.0	1.5	4.0	4.5	ns
t _h	Hold Time, HIGH or LOW D _n to LE	5.0	-2.0	0	0	ns
t _w	LE Pulse Width, HIGH	5.0	2.0	3.0	3.0	ns

Note 5: Voltage Range 5.0 is 5.0V ±0.5V

Capacitance

Symbol Parameter		Тур	Units	Conditions
C _{IN}	Input Capacitance	4.5	pF	V _{CC} = OPEN
C _{PD}	Power Dissipation Capacitance	50.0	pF	V _{CC} = 5.0V



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